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NPN Silicon Epitaxial Transistor

BCP56 Series

These NPN Silicon Epitaxial transistors are designed for use in audio amplifier applications. The device is housed in the SOT-223 package, which is designed for medium power surface mount applications.

Features

- High Current: 1.0 A
- The SOT-223 package can be soldered using wave or reflow. The formed leads absorb thermal stress during soldering, eliminating the possibility of damage to the die
- Available in 12 mm Tape and Reel Use BCP56T1G to Order the 7 inch/1000 Unit Reel Use BCP56T3G to Order the 13 inch/4000 Unit Reel
- PNP Complement is BCP53T1G
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	80	Vdc
Collector-Base Voltage	V _{CBO}	100	Vdc
Emitter-Base Voltage	V _{EBO}	5	Vdc
Collector Current	Ι _C	1	Adc
Collector Current – Peak (Note 1)	I _{CM}	2	Adc
Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 2) Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to 150	°C

THERMAL CHARACTERISTICS

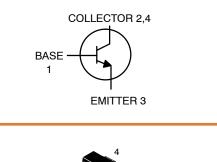
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient (surface mounted)	$R_{ hetaJA}$	83.3	°C/W
Maximum Temperature for Soldering Purposes Time in Solder Bath	ΤL	260 10	°C Sec

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Reference SOA curve.

 Device mounted on a FR-4 glass epoxy printed circuit board 1.575 in x 1.575 in x 0.0625 in; mounting pad for the collector lead = 0.93 sq in.

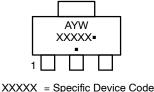
MEDIUM POWER NPN SILICON HIGH CURRENT TRANSISTOR SURFACE MOUNT



2 3 4

SOT-223 CASE 318E STYLE 1

MARKING DIAGRAM



A = Assembly Location Y = Year W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 5.

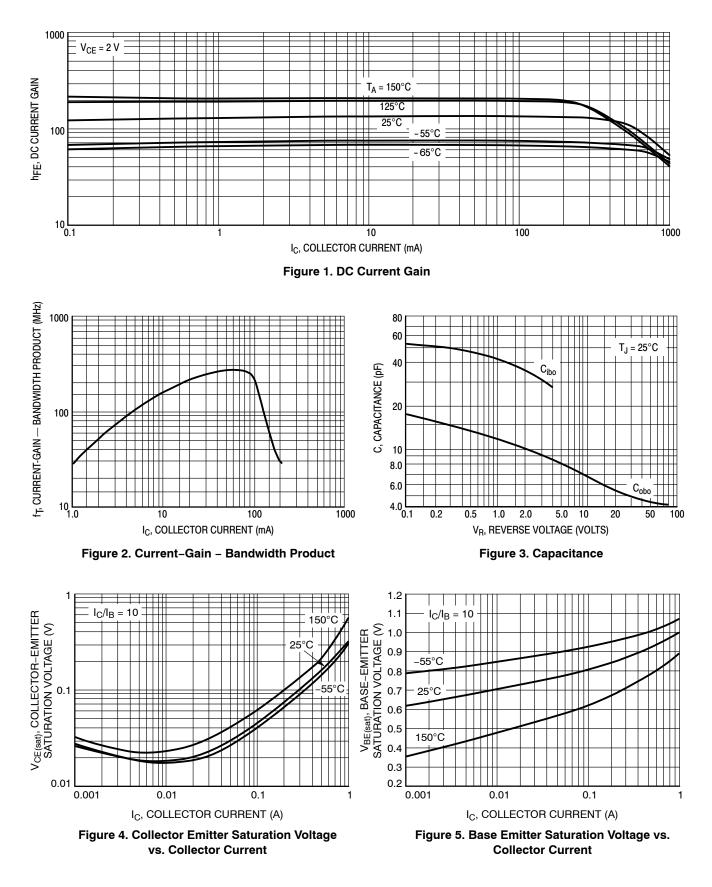
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristics		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–Base Breakdown Voltage ($I_C = 100 \ \mu Adc, I_E = 0$)		V _{(BR)CBO}	100	-	-	Vdc
Collector–Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$		V _{(BR)CEO}	80	-	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = 10 \ \mu Adc, I_C = 0$)		V _{(BR)EBO}	5.0	-	_	Vdc
Collector-Base Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$		I _{CBO}	-	-	100	nAdc
Emitter–Base Cutoff Current (V _{EB} = 5.0 Vdc, I _C = 0)		I _{EBO}	-	-	10	μAdc
ON CHARACTERISTICS (Note 3)						
DC Current Gain (I _C = 5.0 mA, V _{CE} = 2.0 V) (I _C = 150 mA, V _{CE} = 2.0 V) (I _C = 500 mA, V _{CE} = 2.0 V)	All Part Types BCP56 BCP56–10 BCP56–16 All Types	h _{FE}	25 40 63 100 25		_ 250 160 250 _	-
Collector-Emitter Saturation Voltage ($I_C = 500 \text{ mAdc}$, $I_B = 50 \text{ mAdc}$)		V _{CE(sat)}	-	-	0.5	Vdc
Base–Emitter On Voltage (I _C = 500 mAdc, V _{CE} = 2.0 Vdc)		V _{BE(on)}	-	-	1.0	Vdc
SWITCHING CHARACTERISTICS						
Rise Time (V _{CC} = 30 Vdc, I _C = 150 mA, I _{B1} = 15 mA)		t _r	-	14	-	ns
Delay Time (V _{CC} = 30 Vdc, I _C = 150 mA, I _{B1} = 15 mA)		t _d	-	9	_	ns
Storage Time (V _{CC} = 30 Vdc, I _C = 150 mA, I _{B1} = 15 mA, I _{B2} = 15 mA)		t _s	-	714	_	ns
Fall Time (V _{CC} = 30 Vdc, I _C = 150 mA, I _{B1} = 15 mA, I _{B2} = 15 mA)		t _f	-	58	_	ns
DYNAMIC CHARACTERISTICS						
Current Gain Bandwidth Broduct		f-		120		

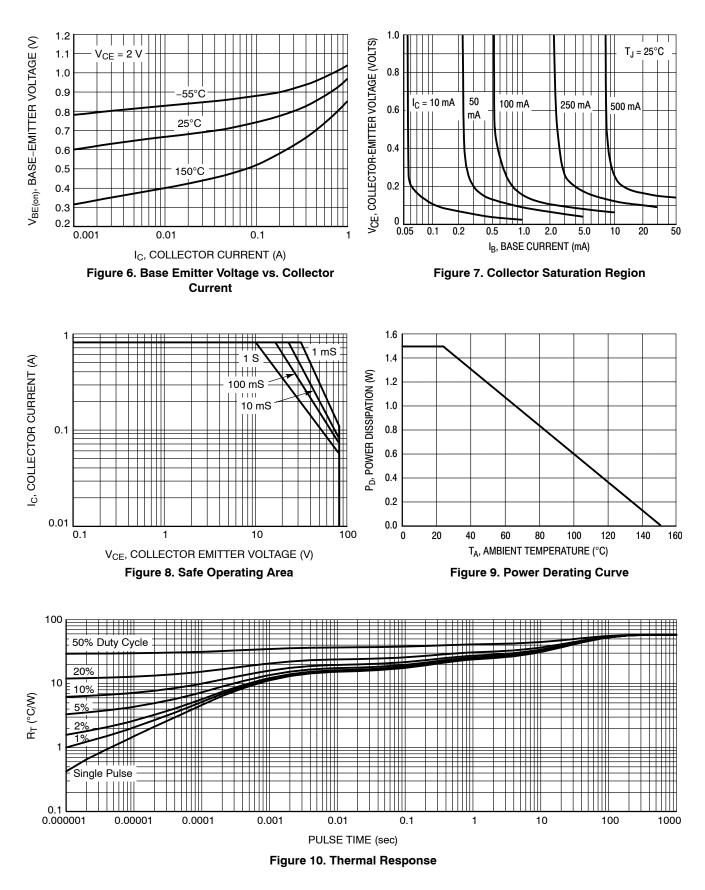
Current–Gain – Bandwidth Product ($I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 35 \text{ MHz}$) MHz f_T 130

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2.0%

TYPICAL ELECTRICAL CHARACTERISTICS



TYPICAL ELECTRICAL CHARACTERISTICS



www.onsemi.com 4

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
BCP56T1G	ВН	SOT-223 (Pb-Free)	1000 / Tape & Reel
SBCP56T1G*			
BCP56T3G	ВН	SOT-223	4000 / Tape & Reel
SBCP56T3G*		(Pb-Free)	
BCP56-10T1G	BH-10	SOT-223	1000 / Tape & Reel
SBCP56-10T1G*		(Pb-Free)	
NSVBCP56-10T3G*	BH-10	SOT-223 (Pb-Free)	4000 / Tape & Reel
BCP56-16T1G	BH-16	SOT-223	1000 / Tape & Reel
SBCP56-16T1G*		(Pb-Free)	
BCP56-16T3G	BH-16	SOT-223	4000 / Tape & Reel
SBCP56-16T3G*		(Pb-Free)	

DISCONTINUED (Note 4)

BCP56-10T3G	BH-10	SOT-223	4000 / Tape & Reel
		(Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable. 4. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most

current information on this device may be available on www.onsemi.com.

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SOT-223 (TO-261) CASE 318E-04 ISSUE R

SEE DETAIL A

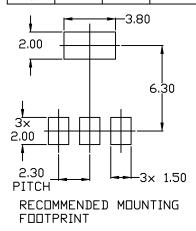
FRONT VIEW

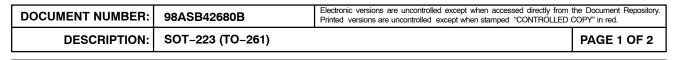
DATE 02 OCT 2018



- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- AI IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
- 6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS & AND &1.

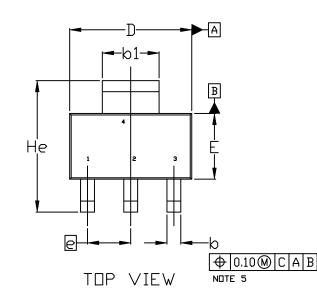
	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
A	1.50	1.63	1.75	
A1	0.02	0.06	0.10	
b	0.60	0.75	0.89	
b1	2.90	3.06	3.20	
с	0.24	0.29	0.35	
D	6.30	6.50	6.70	
E	3.30	3.50	3.70	
e	2.30 BSC			
L	0.20			
L1	1.50	1.75	2.00	
He	6.70	7.00	7.30	
θ	0*		10 °	

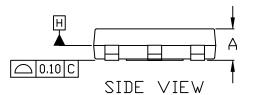


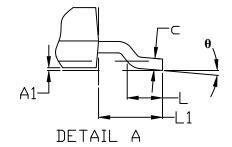


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SCALE 1:1







SOT-223 (TO-261) CASE 318E-04 ISSUE R

DATE 02 OCT 2018

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: Pin 1. Source 2. Drain 3. Gate 4. Drain	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	STYLE 9: Pin 1. Input 2. Ground 3. Logic 4. Ground	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	Style 12: Pin 1. Input 2. Output 3. NC 4. Output	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

GENERIC MARKING DIAGRAM*



- A = Assembly Location
- Y = Year
- W = Work Week
- XXXXX = Specific Device Code
- = Pb-Free Package
- (Note: Microdot may be in either location) *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SOT-223 (TO-261)		PAGE 2 OF 2	

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